

FAST RECOVERY DIODE

ARF220

Repetitive voltage up to	1400 V
Mean forward current	444 A
Surge current	4,5 kA

FINAL SPECIFICATION

May 17 - Issue: 4

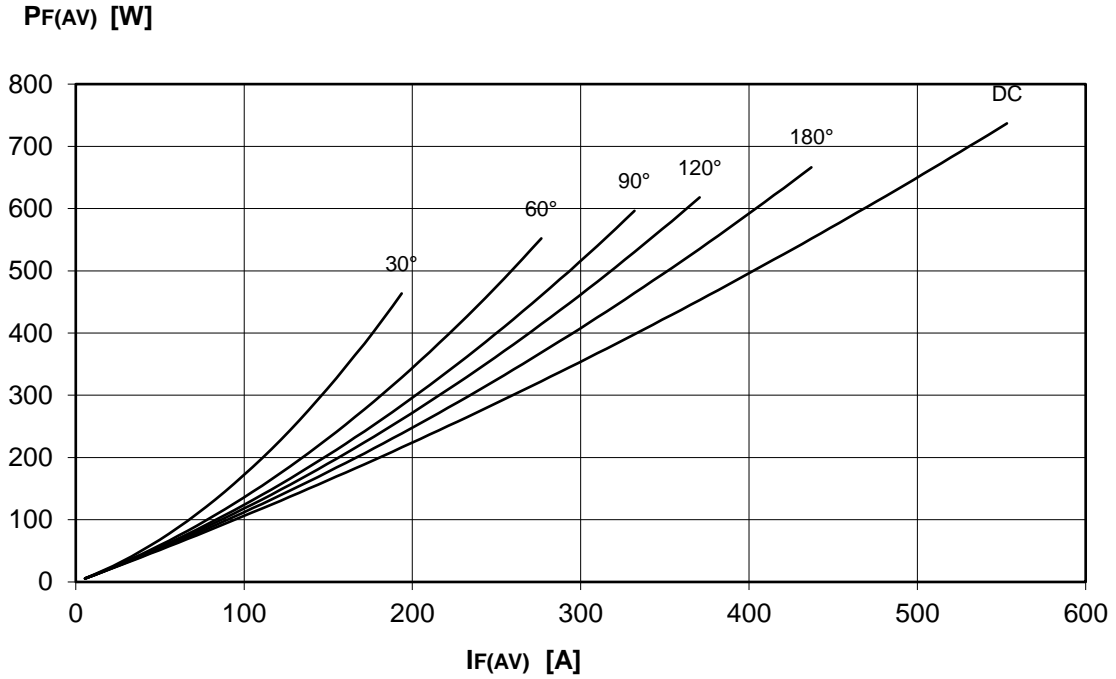
Symbol	Characteristic	Conditions	T _j [°C]	Value	Unit
BLOCKING					
V _{RRM}	Repetitive peak reverse voltage		125	1400	V
V _{RSM}	Non-repetitive peak reverse voltage		125	1500	V
I _{RRM}	Repetitive peak reverse current	V=VRRM	125	50	mA
CONDUCTING					
I _{F(AV)}	Mean forward current	180° sin, 50 Hz, Th=55°C, double side cooled		444	A
I _{F(AV)}	Mean forward current	180°square, 50 Hz, Th=55°C, double side cooled		439	A
I _{FSM}	Surge forward current	Sine wave, 10 ms without reverse voltage	125	4,5	kA
I ² t	I ² t			101 x 10 ³	A ² s
V _{FM}	Forward voltage	Forward current = 300 A	25	1,18	V
V _{F(TO)}	Threshold voltage		125	1,00	V
r _F	Forward slope resistance		125	0,600	mohm
SWITCHING					
t _{rr}	Reverse recovery time	IF= 200A di/dt= 40 A/μs VR= 50V	125	2,5	μs
Q _{rr}	Reverse recovery charge			80	μC
I _{rr}	Peak reverse recovery current			70	A
s	Softness (s-factor), min			0,4	
V _{FR}	Peak forward recovery	di/dt = 400 A/μs	125	15	V
MOUNTING					
R _{th(j-h)}	Thermal impedance, DC	Junction to heatsink, double side cooled		95,0	°C/kW
R _{th(c-h)}	Thermal impedance	Case to heatsink, double side cooled		20,0	°C/kW
T _j	Operating junction temperature			-30 / 125	°C
F	Mounting force			4.5 / 5.0	kN
	Mass			55	g

ORDERING INFORMATION : ARF220 S 14

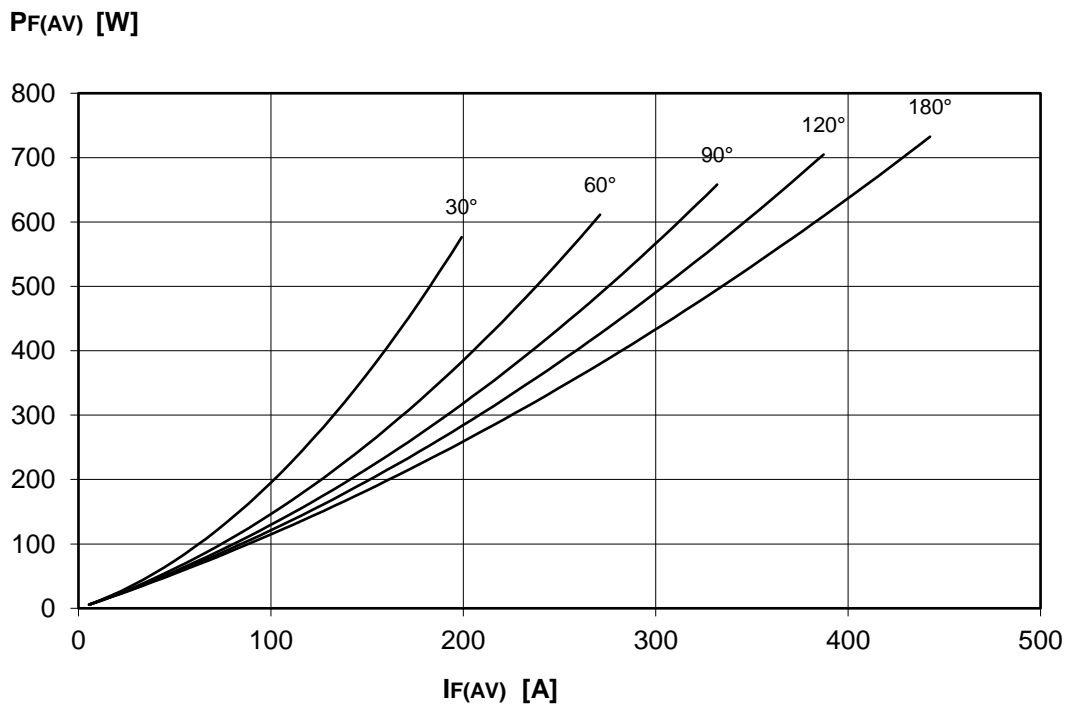
 standard specification VRRM/100

DISSIPATION CHARACTERISTICS

SQUARE WAVE (50Hz)



SINE WAVE (50Hz)

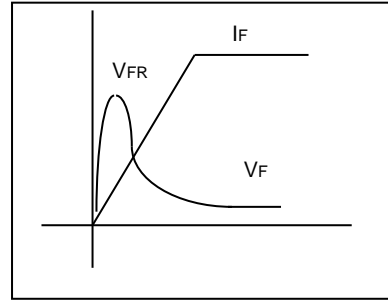
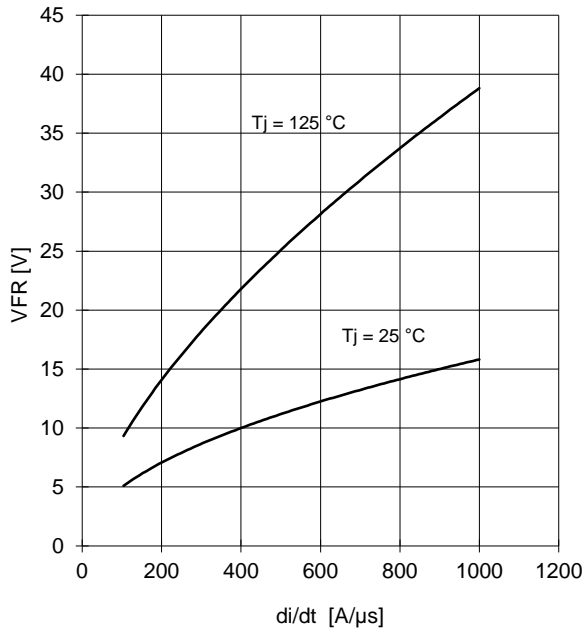


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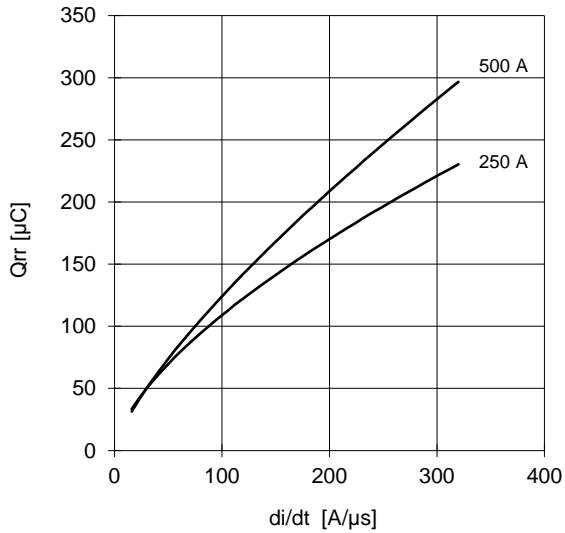


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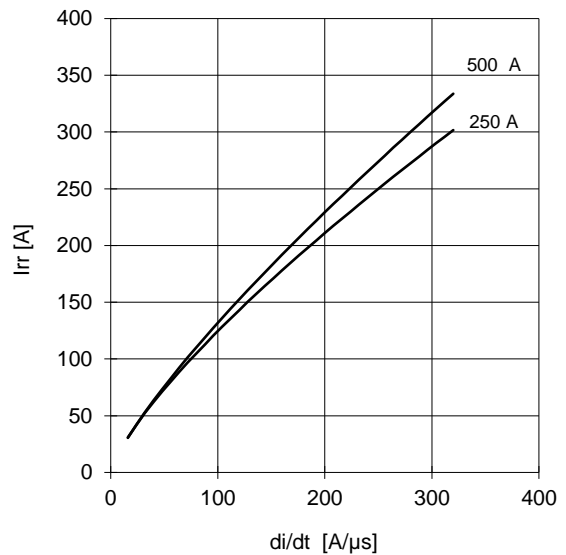
FORWARD RECOVERY VOLTAGE



REVERSE RECOVERY CHARGE Tj = 125 °C



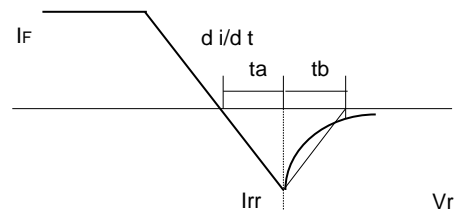
REVERSE RECOVERY CURRENT Tj = 125 °C



$$t_a = I_{rr} / (di/dt) \quad t_b = t_{rr} - t_a$$

$$\text{Softness (s factor)} \quad s = t_b / t_a$$

$$\text{Energy dissipation during recovery } E_r = V_r \cdot (Q_{rr} - I_{rr} \cdot t_a / 2)$$

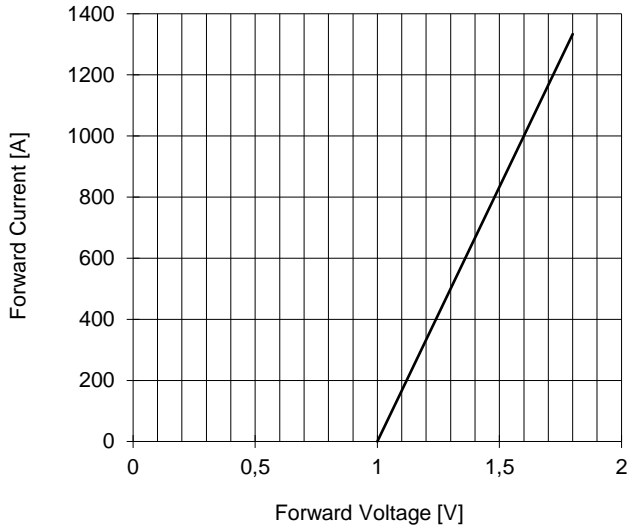


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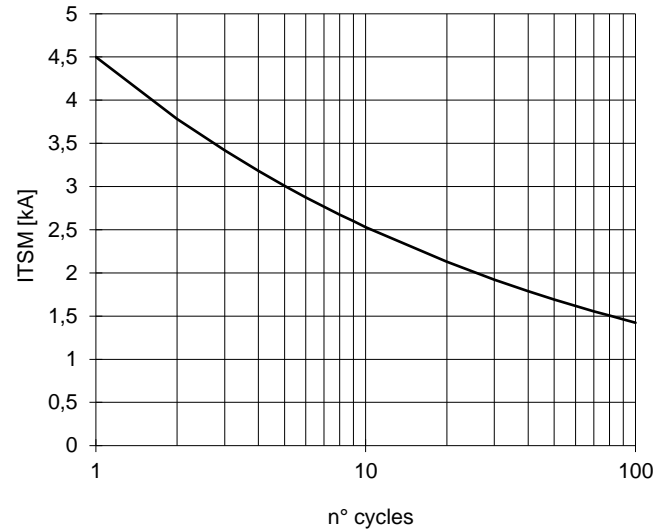


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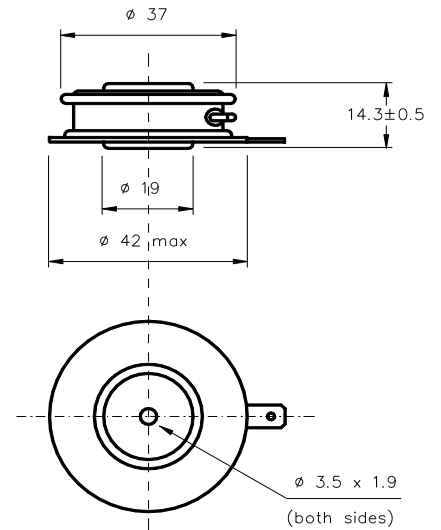
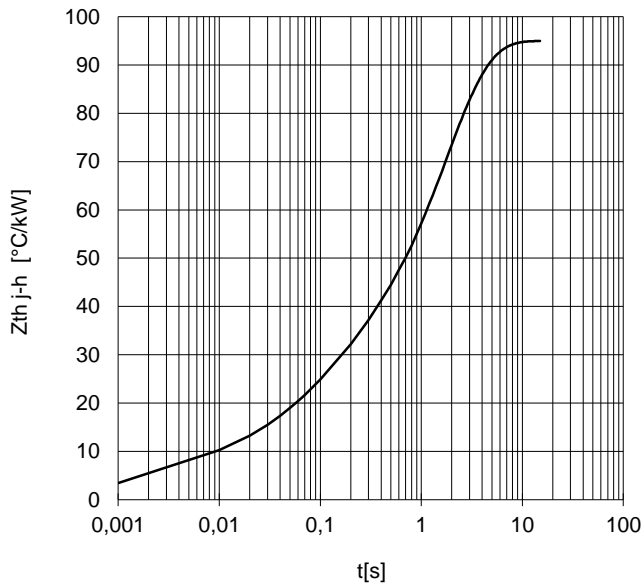
FORWARD CHARACTERISTIC
T_j = 125 °C



SURGE CHARACTERISTIC
T_j = 125 °C



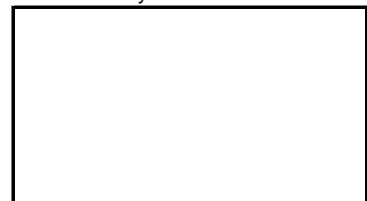
TRANSIENT THERMAL IMPEDANCE
DOUBLE SIDE COOLED



Dimensions
in mm



Distributed by



All the characteristics given in this data sheet are guaranteed only with uniform clamping force, cleaned and lubricated heatsink, surfaces with flatness < .03 mm and roughness < 2 μm. In the interest of product improvement POSEICO SpA reserves the right to change any data given in this data sheet at any time without previous notice. If not stated otherwise the maximum value of ratings (symbols over shaded background) and characteristics is reported.